

Takahisa Shiraishi

List of Publications by Year in descending order

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84
papers

1,334
citations

394421
19
h-index

395702
33
g-index

84
all docs

84
docs citations

84
times ranked

1195
citing authors

#	ARTICLE	IF	CITATIONS
1	Impact of mechanical stress on ferroelectricity in (Hf0.5Zr0.5)O2 thin films. <i>Applied Physics Letters</i> , 2016, 108, .	3.3	187
2	Ferroelectricity mediated by ferroelastic domain switching in HfO2-based epitaxial thin films. <i>Applied Physics Letters</i> , 2018, 113, .	3.3	69
3	Contribution of oxygen vacancies to the ferroelectric behavior of Hf0.5Zr0.5O2 thin films. <i>Applied Physics Letters</i> , 2015, 106, .	3.3	65
4	Growth of (111)-oriented epitaxial and textured ferroelectric Y-doped HfO2 films for downscaled devices. <i>Applied Physics Letters</i> , 2016, 109, .	3.3	62
5	Study on the effect of heat treatment conditions on metalorganic-chemical-vapor-deposited ferroelectric Hf _{0.5} Zr _{0.5} O ₂ thin film on Ir electrode. <i>Japanese Journal of Applied Physics</i> , 2014, 53, 09PA04.	1.5	59
6	Orientation control and domain structure analysis of {100}-oriented epitaxial ferroelectric orthorhombic HfO2-based thin films. <i>Journal of Applied Physics</i> , 2016, 119, .	2.5	57
7	Ferroelectric and Magnetic Properties in Room-temperature Multiferroic Ga _i _x Fe _{2-x} O ₃ Epitaxial Thin Films. <i>Advanced Functional Materials</i> , 2018, 28, 1704789.	14.9	44
8	Effect of the film thickness on the crystal structure and ferroelectric properties of (Hf 0.5 Zr 0.5)O 2 thin films deposited on various substrates. <i>Materials Science in Semiconductor Processing</i> , 2017, 70, 239-245.	4.0	41
9	Solid state epitaxy of (Hf,Zr)O _{<sub>2</sub>} thin films with orthorhombic phase. <i>Journal of the Ceramic Society of Japan</i> , 2016, 124, 689-693.	1.1	34
10	Formation of the orthorhombic phase in CeO2-HfO2 solid solution epitaxial thin films and their ferroelectric properties. <i>Applied Physics Letters</i> , 2019, 114, .	3.3	30
11	Thickness scaling of (Al _{0.8} Sc _{0.2})N films with remanent polarization beyond 100Å ^{1/4} Ccm ² around 10Ånm in thickness. <i>Applied Physics Express</i> , 2021, 14, 105501.	2.4	30
12	Growth of Epitaxial 100-Oriented KNbO ₃ -NbO ₃ Solid Solution Films on (100) _c \$SrRuO ₃ parallel(100)SrTiO ₃ by Hydrothermal Method and Their Characterization. <i>Japanese Journal of Applied Physics</i> , 2011, 50, 09ND11.	1.5	26
13	Crystal structure and dielectric/ferroelectric properties of CSD-derived HfO ₂ -ZrO ₂ solid solution films. <i>Ceramics International</i> , 2017, 43, S501-S505.	4.8	24
14	In-situ observation of ultrafast 90Å° domain switching under application of an electric field in (100)/(001)-oriented tetragonal epitaxial Pb(Zr0.4Ti0.6)O3 thin films. <i>Scientific Reports</i> , 2017, 7, 9641.	3.3	23
15	Fabrication of ferroelectric Fe doped HfO ₂ epitaxial thin films by ion-beam sputtering method and their characterization. <i>Japanese Journal of Applied Physics</i> , 2018, 57, 11UF02.	1.5	23
16	Electric-Field-Induced Ferroelectricity in 5%Y-doped Hf _{0.5} Zr _{0.5} O ₂ : Transformation from the Paraelectric Tetragonal Phase to the Ferroelectric Orthorhombic Phase. <i>Physica Status Solidi - Rapid Research Letters</i> , 2021, 15, 2000589.	2.4	23
17	Crystal Structure Analysis of Hydrothermally Synthesized Epitaxial (K _x Na _{1-x})NbO ₃ Films. <i>Japanese Journal of Applied Physics</i> , 2013, 52, 09KA11.	1.5	22
18	Composition dependency of crystal structure, electrical and piezoelectric properties for hydrothermally-synthesized 3 Åμm-thickness (K _{<sub>i</sub>} _jNa _{<sub>k</sub>})NbO _{<sub>l</sub>} films. <i>Journal of the Ceramic Society of Japan</i> , 2013, 121, 627-631.	1.1	21

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19	Negligible substrate clamping effect on piezoelectric response in (111)-epitaxial tetragonal Pb(Zr, Ti)O ₃ films. <i>Journal of Applied Physics</i> , 2015, 118, .	2.5	21
20	Corrosion and mechanical properties of cast aluminium alloys. <i>International Journal of Cast Metals Research</i> , 2013, 26, 319-329.	1.0	20
21	Ferroelectric and piezoelectric properties of (K,Na)NbO ₃ thick films prepared on metal substrates by hydrothermal method. <i>Journal of the Korean Physical Society</i> , 2013, 62, 1055-1059.	0.7	19
22	Vibration-energy-harvesting properties of hydrothermally synthesized (K,Na)NbO ₃ films deposited on flexible metal foil substrates. <i>Japanese Journal of Applied Physics</i> , 2015, 54, 10ND06.	1.5	18
23	Effects of starting materials on the deposition behavior of hydrothermally synthesized {100}-oriented epitaxial (K,Na)NbO ₃ thick films and their ferroelectric and piezoelectric properties. <i>Journal of Crystal Growth</i> , 2019, 511, 1-7.	1.5	18
24	Domain orientation relationship of orthorhombic and coexisting monoclinic phases of YO _{1.5} -doped HfO ₂ epitaxial thin films. <i>Japanese Journal of Applied Physics</i> , 2018, 57, 11UF16.	1.5	16
25	Demonstration of ferroelectricity in ScGaN thin film using sputtering method. <i>Applied Physics Letters</i> , 2021, 119, .	3.3	15
26	Crystallisation characteristics of primary silicon particles in cast hypereutectic Al-Si alloy. <i>International Journal of Cast Metals Research</i> , 2013, 26, 105-113.	1.0	14
27	Ferroelectric and piezoelectric properties of KNbO ₃ films deposited on flexible organic substrate by hydrothermal method. <i>Japanese Journal of Applied Physics</i> , 2014, 53, 09PA10.	1.5	14
28	Crystal structure and magnetism in $\tilde{\text{A}}$ -Al ₂ O ₃ -type Al _x Fe _{2-x} O ₃ films on SrTiO ₃ (111). <i>Journal of Applied Physics</i> , 2017, 122, 015301.	2.5	14
29	Growth of 130 $\tilde{\mu}$ m Thick Epitaxial KNbO ₃ Film by Hydrothermal Method. <i>Materials Research Society Symposia Proceedings</i> , 2013, 1494, 291-296.	0.1	13
30	Epitaxial PbZr _x Ti _{1-x} O ₃ Ferroelectric Bilayers with Giant Electromechanical Properties. <i>Advanced Materials Interfaces</i> , 2015, 2, 1500075.	3.7	13
31	Switchable third ScFeO ₃ polar ferromagnet with YMnO ₃ -type structure. <i>Journal of Materials Chemistry C</i> , 2020, 8, 4447-4452.	5.5	13
32	Growth of epitaxial (K, Na)NbO ₃ films with various orientations by hydrothermal method and their properties. <i>Japanese Journal of Applied Physics</i> , 2019, 58, SLLB14.	1.5	11
33	Enhancement of crystal anisotropy and ferroelectricity by decreasing thickness in (Al,Sc)N films. <i>Journal of the Ceramic Society of Japan</i> , 2022, 130, 436-441.	1.1	11
34	Large irreversible non-180° domain switching after poling treatment in Pb(Zr, Ti)O ₃ films. <i>Applied Physics Letters</i> , 2016, 108, .	3.3	10
35	Characterization of (111)-oriented epitaxial (K _{0.5} Na _{0.5})NbO ₃ thick films deposited by hydrothermal method. <i>Japanese Journal of Applied Physics</i> , 2017, 56, 10PF04.	1.5	10
36	Preparation of {001}c-oriented epitaxial (K, Na)NbO ₃ thick films by repeated hydrothermal deposition technique. <i>Journal of the Ceramic Society of Japan</i> , 2018, 126, 281-285.	1.1	10

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37	Thermal stability of self-polarization in a (K,Na)NbO ₃ film prepared by the hydrothermal method. Japanese Journal of Applied Physics, 2021, 60, SFFB03.	1.5	10
38	Growth of Epitaxial 100-Oriented KNbO ₃ -NbO ₃ Solid Solution Films on (100)cSrRuO ₃ -(100)SrTiO ₃ by Hydrothermal Method and Their Characterization. Japanese Journal of Applied Physics, 2011, 50, 09ND11.	1.5	10
39	High yield preparation of (100)-oriented (K,Na)NbO ₃ thick films by hydrothermal method using amorphous niobium source. Journal of the Ceramic Society of Japan, 2020, 128, 512-517.	1.1	9
40	Domain structure of tetragonal Pb(Zr,Ti)O ₃ nanorods and its size dependence. Japanese Journal of Applied Physics, 2015, 54, 10NA07.	1.5	8
41	Thermally stable dielectric responses in uniaxially (001)-oriented CaBi ₄ Ti ₄ O ₁₅ nanofilms grown on a Ca ₂ Nb ₃ O ₁₀ nanosheet seed layer. Scientific Reports, 2016, 6, 20713.	3.3	8
42	Strain-induced nanostructure of Pb(Mg _{1/3} Nb _{2/3})O ₃ -PbTiO ₃ epitaxial thin films with low PbTiO ₃ concentration. Japanese Journal of Applied Physics, 2017, 56, 10PB12.	1.5	8
43	Formation of polar phase in Fe-doped ZrO ₂ epitaxial thin films. Applied Physics Letters, 2018, 113, .	3.3	8
44	Effect of Ta-substitution on the deposition of (K,Na)(Nb,Ta)O ₃ films by hydrothermal method. Japanese Journal of Applied Physics, 2019, 58, SLB12.	1.5	8
45	Good piezoelectricity of self-polarized thick epitaxial (K,Na)NbO ₃ films grown below the Curie temperature (240°C) using a hydrothermal method. Applied Physics Letters, 2020, 117, .	3.3	8
46	Structural and electrical characterization of hydrothermally deposited piezoelectric (K,Na)(Nb,Ta)O ₃ thick films. Journal of Materials Science, 2020, 55, 8829-8842.	3.7	8
47	Low-temperature deposition of Li substituted (K,Na)NbO ₃ films by a hydrothermal method and their structural and ferroelectric properties. Journal of the Ceramic Society of Japan, 2019, 127, 388-393.	1.1	8
48	Composition dependence of ferroelectric properties in (111)-oriented epitaxial HfO ₂ -CeO ₂ solid solution films. Japanese Journal of Applied Physics, 2022, 61, SN1019.	1.5	8
49	Effects of heat treatment on electrical and electromechanical properties of hydrothermally synthesized epitaxial (K _{0.51} Na _{0.49})NbO ₃ films. Japanese Journal of Applied Physics, 2014, 53, 05FE02.	1.5	7
50	Effect of incubation time on preparation of continuous and flat Ru films. Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films, 2015, 33, .	2.1	7
51	Crystal structure and compositional analysis of epitaxial (K _{0.56} Na _{0.44})NbO ₃ films prepared by hydrothermal method. Journal of Materials Research, 2016, 31, 693-701.	2.6	7
52	Deposition of orientation-controlled thick (K,Na)NbO ₃ films on metal substrates by repeated hydrothermal deposition technique. Journal of the Ceramic Society of Japan, 2019, 127, 478-484.	1.1	7
53	Rapid deposition of (K,Na)NbO ₃ thick films using microwave-assisted hydrothermal technique. Japanese Journal of Applied Physics, 2020, 59, SPPB02.	1.5	7
54	Ferroelectric and piezoelectric properties of 100-nm-thick CeO ₂ -HfO ₂ epitaxial films. Applied Physics Letters, 2022, 120, .	3.3	7

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55	Structural evolution of epitaxial CeO ₂ -HfO ₂ thin films using atomic-scale observation: Formation of ferroelectric phase and domain structure. <i>Acta Materialia</i> , 2022, 235, 118091.	7.9	7
56	Short range biaxial strain relief mechanism within epitaxially grown BiFeO ₃ . <i>Scientific Reports</i> , 2019, 9, 6715.	3.3	6
57	Influence of cooling rate on ferroelastic domain structure for epitaxial (100)/(001)-oriented Pb(Zr, Ti)O ₃ . <i>Journal of Applied Physics</i> , 2015, 118, 074314.	1.5	6
58	Polar-axis-oriented epitaxial tetragonal (Bi,K)TiO ₃ films with large remanent polarization deposited below Curie temperature by a hydrothermal method. <i>Applied Physics Letters</i> , 2022, 120, 022903.	3.3	6
59	Mechanical properties of AC4CH alloys produced by heated mould continuous casting process. <i>International Journal of Cast Metals Research</i> , 2013, 26, 160-167.	1.0	5
60	Strain induced martensite formation characteristics of austenite stainless steel during various loading conditions. <i>Materials Science and Technology</i> , 2014, 30, 301-308.	1.6	5
61	Growth mechanism and domain structure study on epitaxial BiFeO ₃ film grown on (La _{0.3} Sr _{0.7})(Al _{0.65} Ta _{0.35})O ₃ . <i>Journal of Applied Physics</i> , 2020, 127, .	2.5	5
62	Energy storage properties of epitaxially grown CaZrO ₃ -(1-x)NaNbO ₃ thin films prepared with chemical solution deposition method. <i>Journal of Applied Physics</i> , 2020, 128, .	2.5	5
63	Effect of film thickness on piezoelectric vibrator using hydrothermally synthesized epitaxial (K _{0.88} Na _{0.12})NbO ₃ film. <i>Japanese Journal of Applied Physics</i> , 2022, 61, SN1016.	1.5	5
64	Interface structure of Pb(Zr,Ti)O ₃ /MgO(001) epitaxial thin film in early stage of Stranski-Krastanov growth mode. <i>Japanese Journal of Applied Physics</i> , 2019, 58, SLLA08.	1.5	4
65	Evaluation of spatial and temporal resolution on in situ annealing aberration-corrected transmission electron microscopy with proportional integral-differential controller. <i>Microscopy (Oxford)</i> , 2013, 10, 784-794.	1.5	4
66	Redox-Based Multilevel Resistive Switching in AlFeO ₃ Thin-Film Heterostructures. <i>ACS Applied Electronic Materials</i> , 2020, 2, 1065-1073.	4.3	4
67	Epitaxial growth mechanism of Pb(Zr,Ti)O ₃ thin films on SrTiO ₃ by chemical solution deposition via self-organized seed layer. <i>Journal of the Ceramic Society of Japan</i> , 2020, 128, 501-511.	1.1	4
68	Effect of domain wall characteristics on material properties of lead zirconate titanate piezoelectric ceramics. <i>Advances in Applied Ceramics</i> , 2012, 111, 187-195.	1.1	3
69	Low Temperature Preparation of KNbO₃Films by Hydrothermal Method and Their Characterization. <i>Materials Research Society Symposia Proceedings</i> , 2014, 1659, 49-54.	0.1	3
70	rhombohedral epitaxial <mml:math>\text{Pb}(\text{Zr},\text{Ti})\text{O}_3</mml:math> nanorods by focused ion beam and characterization of the domain structure. <i>Physical Review B</i> , 2019, 100, .	3.2	3
71	Fabrication of tetragonal Pb(Zr,Ti)O ₃ nanorods by focused ion beam and characterization of the domain structure. <i>Journal of Materials Science</i> , 2015, 52, 6950-6961.	2	2
72	The microstructural evolution in high sodium epitaxial sodium potassium niobate films deposited by low-temperature hydro-thermal method. <i>Journal of Materials Science</i> , 2017, 52, 6950-6961.	3.7	2

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73	Interface reaction between PbTiO ₃ epitaxial thin films and La-doped SrTiO ₃ (001) substrates through edge dislocations induced by 90° domain formation. Journal of the Ceramic Society of Japan, 2020, 128, 492-500.	1.1	2
74	Polarization switching behavior of one-axis-oriented lead zirconate titanate films fabricated on metal oxide nanosheet layer. Japanese Journal of Applied Physics, 2017, 56, 10PF10.	1.5	2
75	No-Heating Deposition of 1.4 nm Thick Y-doped HfO ₂ Ferroelectric Films with Good Ferroelectric and Piezoelectric Properties by Radio Frequency Magnetron Sputtering Method. Physica Status Solidi - Rapid Research Letters, 2022, 16, .	2.4	2
76	Film thickness dependence of ferroelectric properties in polar-axis-oriented epitaxial tetragonal (Bi,K)TiO ₃ films prepared by hydrothermal method. AIP Advances, 2022, 12, 035241.	1.3	2
77	Electric-Field-Induced Ferroelectricity in 5%Y-doped Hf _{0.5} Zr _{0.5} O ₂ : Transformation from the Paraelectric Tetragonal Phase to the Ferroelectric Orthorhombic Phase. Physica Status Solidi - Rapid Research Letters, 2021, 15, 2170023.	2.4	1
78	Effect of Ta substitution on the synthesis of (K,Na)(Nb,Ta)O ₃ powders by hydrothermal reaction: Insight into the combination of alkaline solution and raw powder. Journal of the Ceramic Society of Japan, 2021, 129, 365-371.	1.1	1
79	Lower-temperature processing of potassium niobate films by microwave-assisted hydrothermal deposition technique. Journal of the Ceramic Society of Japan, 2022, 130, 123-130.	1.1	1
80	Evaluation of bulk and surface acoustic waves propagation properties of (K,Na)NbO ₃ films deposited by hydrothermal synthesis or RF magnetron sputtering methods. Japanese Journal of Applied Physics, 2022, 61, SG1077.	1.5	1
81	Study of resonance fatigue properties of piezoelectric ceramics using new fatigue testing system. Advances in Applied Ceramics, 2012, 111, 181-186.	1.1	0
82	Texture Observation for α -Fe ₂ O ₃ Doped HfO ₂ Ultrathin Films. Materia Japan, 2016, 55, 599-599.	0.1	0
83	Hydrothermal Deposition of KNbO ₃ Films on Metal Substrates having Three-Dimensional Structure. Funtai Oyobi Fumatsu Yakin/Journal of the Japan Society of Powder and Powder Metallurgy, 2018, 65, 673-677.	0.2	0
84	Misfit Strain Induced Interface Structure in PMN-PT Epitaxial Thin Films. Materia Japan, 2019, 58, 97-97.	0.1	0